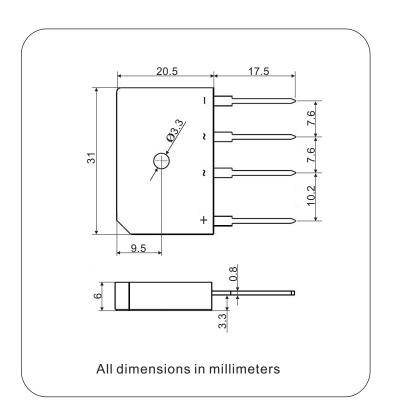


## Nell High Power Products

# Single-Phase Bridge Rectifier, 50A KBJ5004 Thru KBJ5012

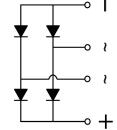




### **FEATURES**

- UL recognition file number E320098
- Typical IR less than 2.0 μA
- High surge current capability
- Low thermal resistance
- Compliant to RoHS
- Isolation voltage up to 2500V





### **TYPICAL APPLICATIONS**

General purpose use in AC/DC bridge full wave rectification for big power supply, field supply for DC motor, industrial automation applications.

#### **ADVANTAGE**

- International standard package
  Epoxy meets UL 94 V-O flammability rating
- Small volume, light weight
- Small thermal resistance
- High heat-conduction rate
- Low temperature rise
- Weight: 10g (0.35 ozs)

PRIMARY CHARACTERRISTICS						
I <sub>F(AV)</sub>	50A					
$V_{RRM}$	400V to 1200V					
I <sub>FSM</sub>	450A					
I <sub>R</sub>	5 μΑ					
V <sub>F</sub>	1.10V					
T <sub>J max</sub> .	150°C					





## **Nell High Power Products**

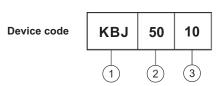
MAJOR RATINGS AND CHARACTERISTICS (T <sub>A</sub> = 25°C unless otherwise noted)									
PARAMETER	SYMBOL	KBJ50							
		04	06	08	10	12	UNIT		
Maximum repetitive peak reverse voltage	$V_{RRM}$	400	600	800	1000	1200	V		
Peak reverse non-repetitive voltage	V <sub>RSM</sub>	500	700	900	1100	1300	V		
Maximum DC blocking voltage	$V_{DC}$	400	600	800	1000	1200	V		
Maximum average forward rectified output current	I <sub>F(AV)</sub>	50					Α		
Peak forward surge current single sine-wave superimposed on rated load	I <sub>FSM</sub>	450					А		
Rating (non-repetitive, for t greater than 1 ms and less than 8.3 ms) for fusing	I <sup>2</sup> t	1012				A <sup>2</sup> s			
RMS isolation voltage from case to leads	V <sub>ISO</sub>	2500				V			
Operating junction storage temperature range	TJ	-40 to 150				°C			
Storage temperature range	T <sub>STG</sub>	-40 to 125				°C			

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25°C unless otherwise noted)									
PARAMETER	TEST	SYMBOL	KBJ50						
CONDITION		STWIDOL	04	06	08	10	12	UNIT	
Maximum instantaneous forward drop per diode	I <sub>F</sub> = 25A	V <sub>F</sub>	1.10					V	
Maximum reverse DC current at rated DC blocking	T <sub>A</sub> = 25°C	5					μА		
voltage per diod	T <sub>A</sub> = 150°C	IR	500						

THERMAL AND MECHANICAC (T <sub>A</sub> = 25°C unless otherwise noted)									
PARAMETER	TEST CONDITIONS	SYMBOL	KBJ50						
PARAMETER TEST CONDITIONS		STIVIBUL	04	06	08	10	12	UNIT	
Typical thermal resistance junction to case	Single-side heat dissipation, sine half wave	$R_{\theta JC}^{_{(1)}}$			1.0			°C/W	
Mounting torque to heatsink M3 ± 10 %	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound.		2.5			Nm			
Approximate weight					10			g	

#### Notes

- (1) With heatsink, single side heat dissipation, half sine wave.
- (2) M3 screw.

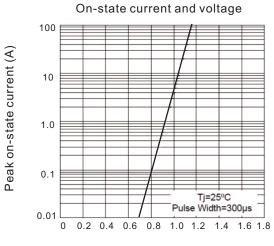


- 1 Module type: "KBJ" Package , 1Ø Bridge
- 2 I<sub>F(AV)</sub> rating:"50" for 50A
- 3 Voltage code:code x 100 = V<sub>RRM</sub>





## **Nell High Power Products**



Peak on-state voltage (V)

### Case temperature vs on-state average current

